

Description

The DIODES™ AP7375 series is a wide input voltage range (45V), low quiescent current (2.1µA), low-dropout linear regulator (LDO) able to provide 300mA load current. The AP7375 family LDO offers an EN pin that takes an input voltage of 45V to enable and disable the LDO output.

The device features very fast response times against line voltage transient and load current transient, and ensures no overshoot voltage during start-up and short-circuit recovery. It also features integrated short-circuit and thermal shutdown protection.

The AP7375 has 1.8V, 3.0V, 3.3V, and 5.0V fixed output voltage versions, and is available in the SOT23, SOT25, and SOT89 packages.

Features

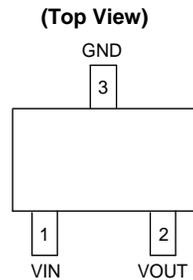
- Wide Input Voltage Range: 3V to 45V
- Maximum Output Current: 300mA
- Low Dropout Voltage:
 - $V_{DRO} = 35mV @ I_{OUT} = 10mA$ (Typ.)
 - $V_{DRO} = 350mV @ I_{OUT} = 100mA$ (Typ.)
- Low Quiescent Current: 2.1µA (Typ.)
- Fixed Output Voltages: 1.8V, 3.0V, 3.3V and 5.0V
- High Output Voltage Accuracy: ±2%
- High PSRR: 85dB@1kHz
- Excellent Line/Load Regulation
- Thermal Shutdown Function
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Applications

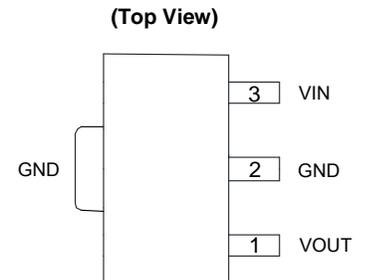
- Battery-powered equipment
- Smoke detectors and sensors
- Microcontroller applications
- Home appliances

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

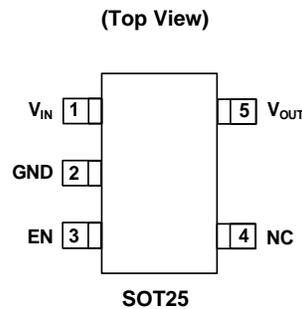
Pin Assignments



SOT23

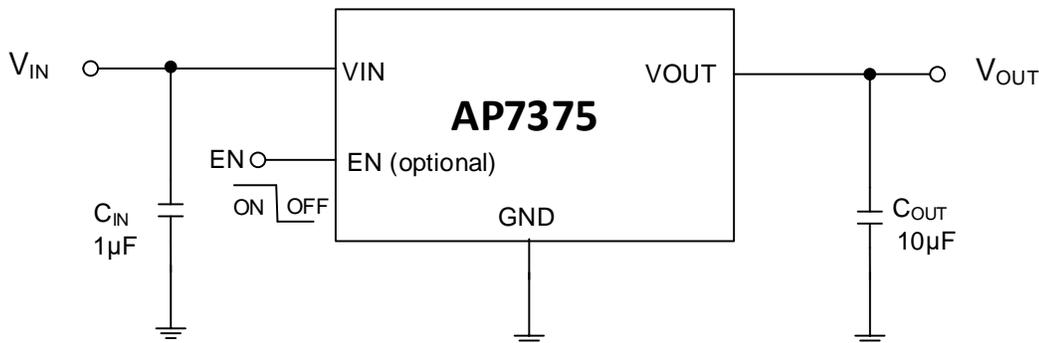


SOT89



SOT25

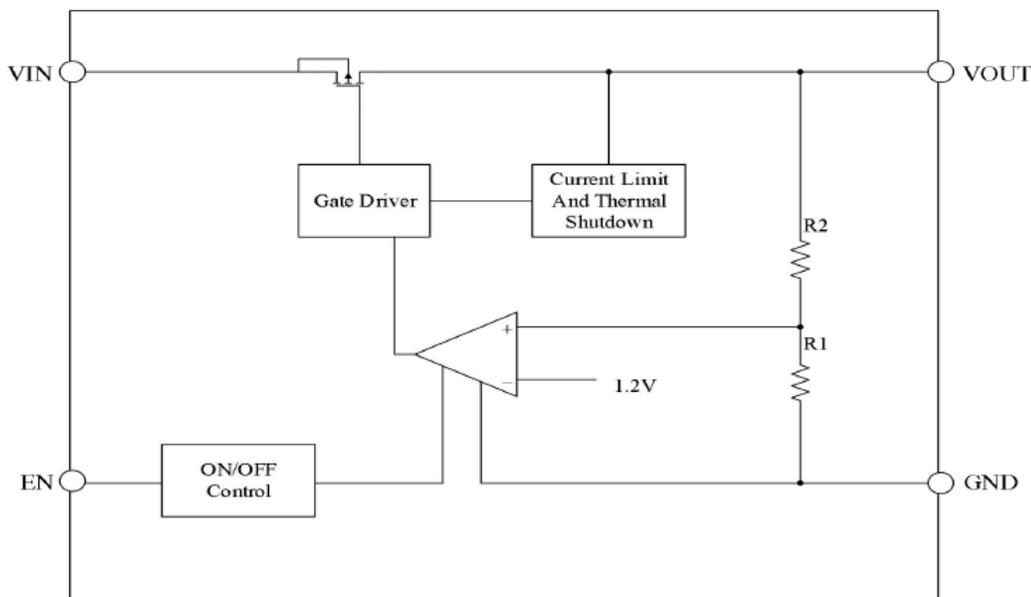
Typical Applications Circuit



Pin Descriptions

Pin Number			Pin Name	Function
SOT25	SOT23	SOT89		
1	1	3	VIN	Input voltage
2	3	2	GND	Ground
3	-	-	EN	Enable
5	2	1	VOUT	Regulated output voltage
4	-	-	NC	Not Connected internally, recommend connect to GND to maximize PCB copper for thermal dissipation.

Functional Block Diagram



Absolute Maximum Ratings (Note 4) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
V_{IN}	Supply Input Voltage	-0.3 ~ 55	V	
V_{OUT}	Regulated Output Voltage	-0.3 ~ 6	V	
	V_{OUT} to V_{IN}	-55 ~ 0.3	V	
V_{EN}	EN to GND	-0.3 ~ 55	V	
I_{OUT}	Output Current	Internally limited	mA	
T_{LEAD}	Lead Temperature (Soldering, 10sec)	+260	$^\circ\text{C}$	
T_J	Operating Junction Temperature	+150	$^\circ\text{C}$	
T_A	Operating Ambient Temperature	-40 to +85	$^\circ\text{C}$	
θ_{JA}	Thermal Resistance (Junction to Ambient)	SOT25	153	$^\circ\text{C}/\text{W}$
		SOT23	164	
		SOT89	95	
T_{STG}	Storage Temperature Range	-40 to +150	$^\circ\text{C}$	
CDM	ESD (Change Device Model)	1.5kV	V	
HBM	ESD (Human Body Model)	4kV	V	

Note: 4. a). Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to absolute-maximum-rated conditions for extended period may affect device reliability.
 b). Ratings apply to ambient temperature at +25°C. The JEDEC STD.51 High-K board design used to derive this data was a 3 inch x 3 inch multilayer board with 1oz. internal power and ground planes and 2oz. copper traces on the top and bottom of the board.

Recommended Operating Conditions

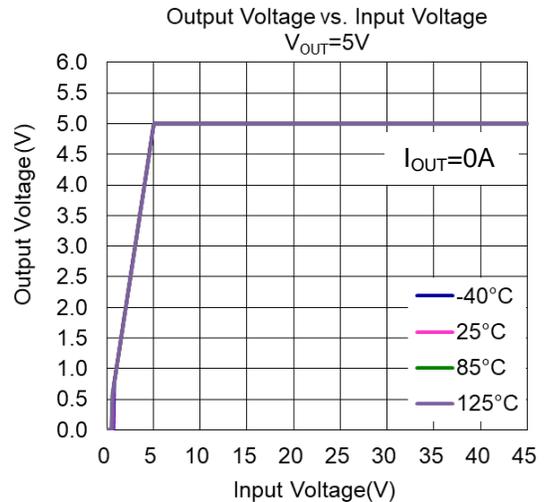
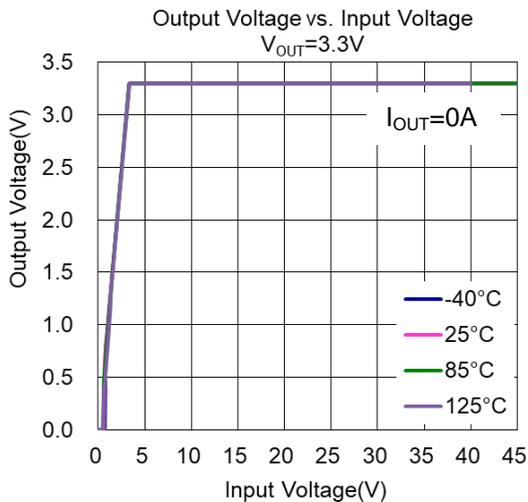
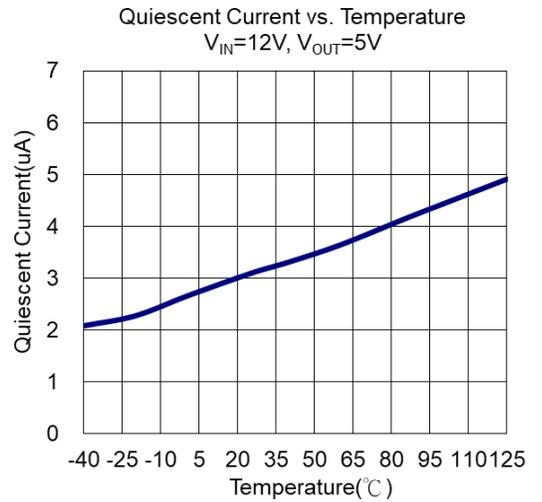
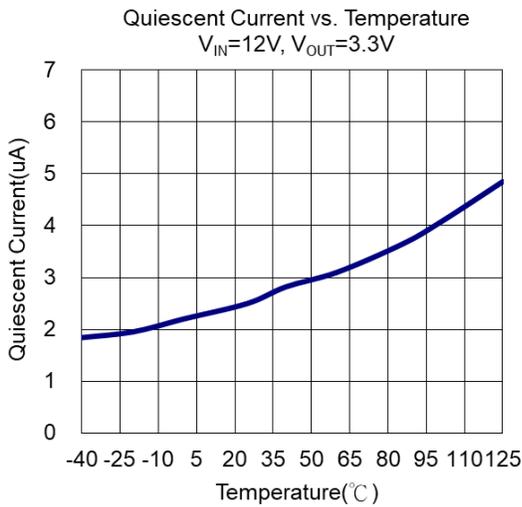
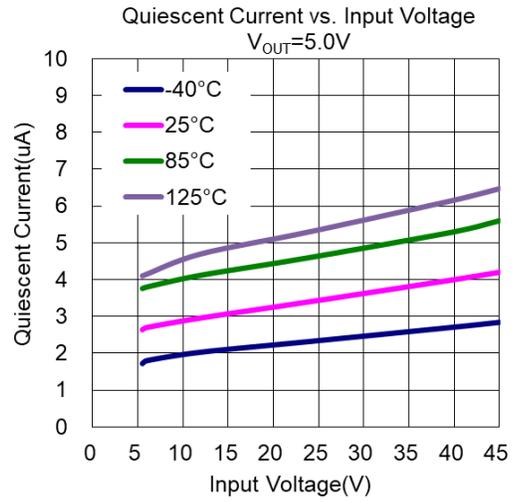
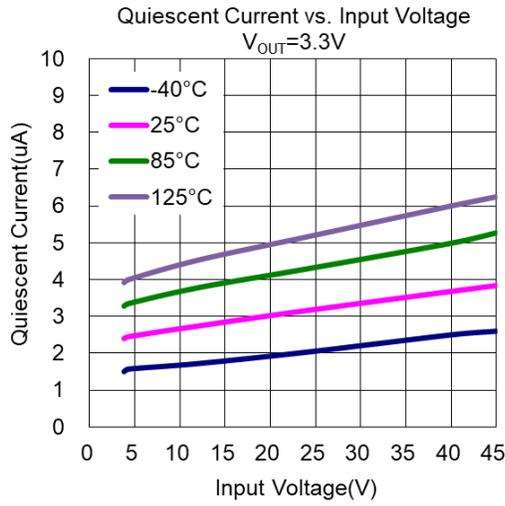
Symbol	Parameter	Min	Max	Unit
V _{IN}	Supply Input Voltage	3.0	45	V
V _{OUT}	Output Voltage	—	5	V
T _J	Operating Junction Temperature	-40	+125	°C

Electrical Characteristics (T_A = 25°C, I_{OUT} = 1mA, C_{IN} = 1μF, C_{OUT} = 10μF ceramic capacitor, V_{IN} = V_{OUTNOM} + 2.0V)

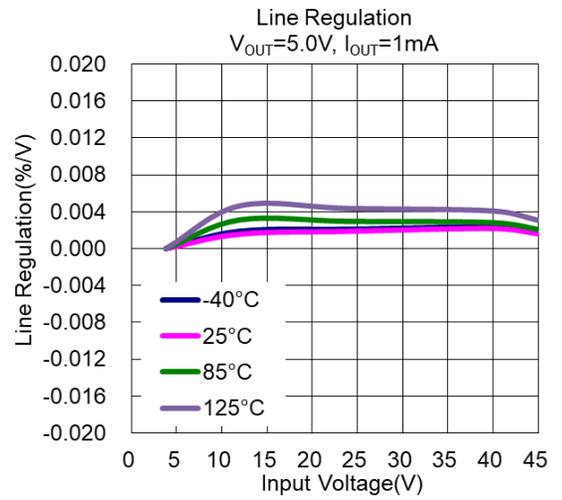
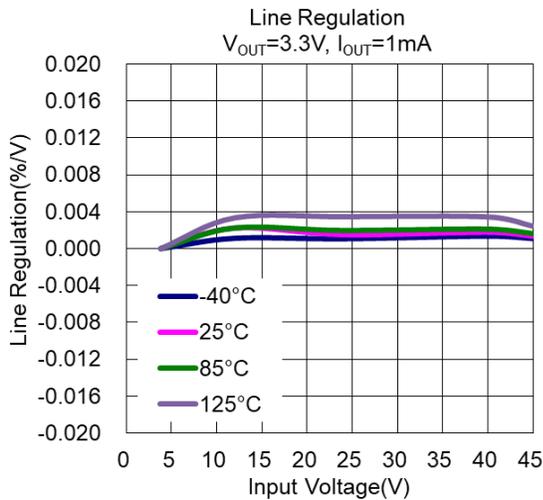
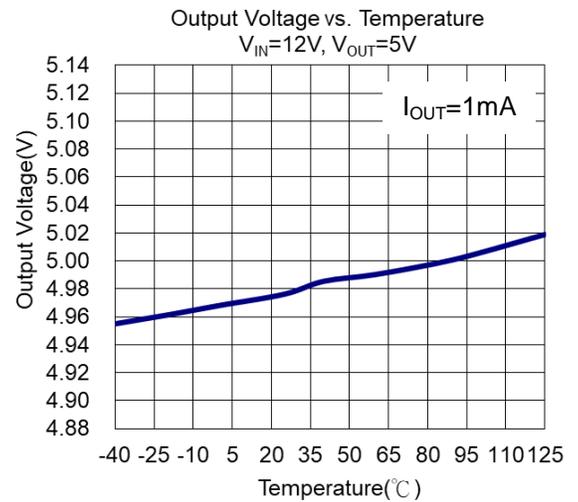
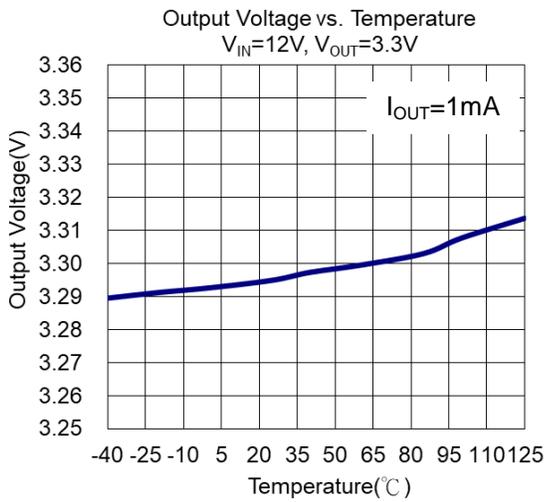
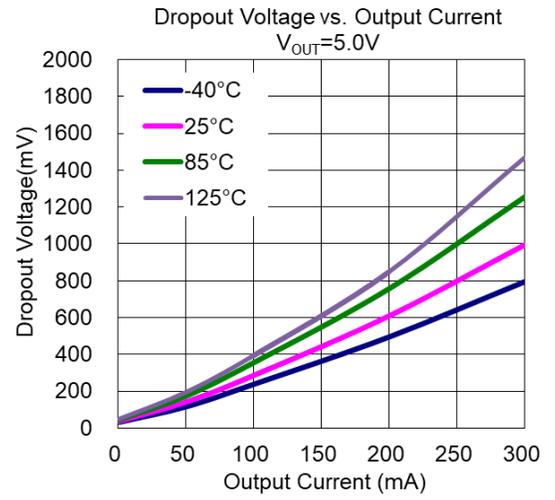
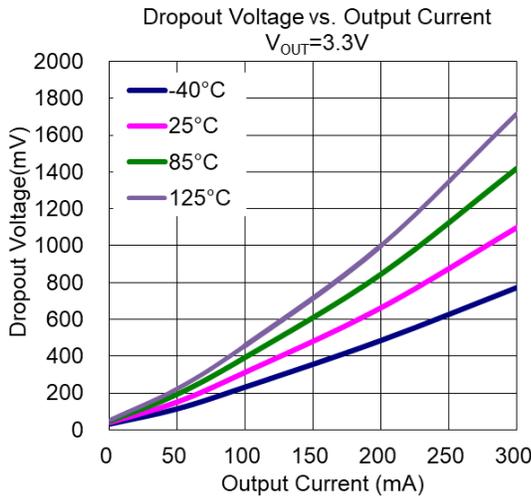
Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{IN}	Input Voltage	—	3	—	45	V
I _{IGND}	Quiescent Current	V _{IN} = 12V, No load	—	2.1	5	μA
V _{OUT}	Output Voltage	V _{IN} = 12V, I _{OUT} = 10 mA	V _{OUT} × 98%	—	V _{OUT} × 102%	V
I _{OUT_MAX}	Output Current	—	300	350	—	mA
V _{DROP}	Dropout Voltage	I _{OUT} = 10mA, V _{IN} = V _{OUTNOM} - 0.1V	—	35	50	mV
		I _{OUT} = 100mA, V _{IN} = V _{OUTNOM} - 0.1V	—	350	360	mV
ΔV _{OUT} (ΔI _{OUT})	Load Regulation (Note 5)	V _{IN} = 12V, 1mA ≤ I _{OUT} ≤ 100mA	—	0.02	0.025	%/mA
ΔV _{OUT} (ΔV _{IN})	Line Regulation	V _{OUTNOM} + 0.5 V ≤ V _{IN} ≤ 45 V, I _{OUT} = 1 mA	—	0.01	0.02	%/V
I _{LIMIT}	Current Limit	—	—	500	—	mA
T _{OTSD}	Thermal Shutdown Temperature	—	—	+150	—	°C
T _{HYOTSD}	Thermal Shutdown Hysteresis	—	—	+20	—	°C
PSRR	Power Supply Rejection Ratio	V _{IN} = 12V, I _{OUT} = 10mA, V _{OUT} = 3.3V @ 1kHz	—	85	—	dB
VENH	EN High Level	Enabled	1	—	—	V
VENL	EN Low Level	Disabled	—	—	0.4	V
θ _{JC}	Thermal Resistance Junction to Case (Note 4)	SOT25	—	54	—	°C/W
		SOT23	—	85	—	
		SOT89	—	44	—	

- Note:
4. a). Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to absolute-maximum-rated conditions for extended period may affect device reliability.
 - b). Ratings apply to ambient temperature at +25°C. The JEDEC STD.51 High-K board design used to derive this data was a 3 inch x 3 inch multilayer board with 1oz. internal power and ground planes and 2oz. copper traces on the top and bottom of the board.
 5. The AP7375 internal circuitry is not fully operation until V_{IN} is at least the greater of 3V or (V_{OUT} + V_{DROPOUT(MAX)}).

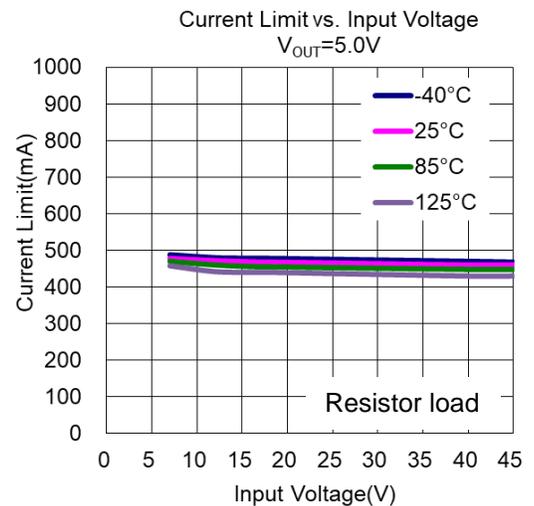
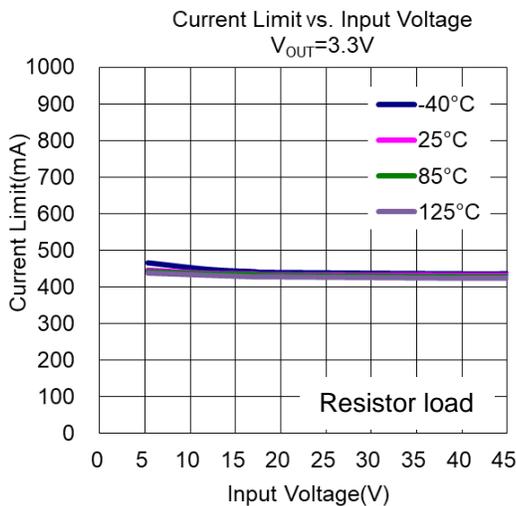
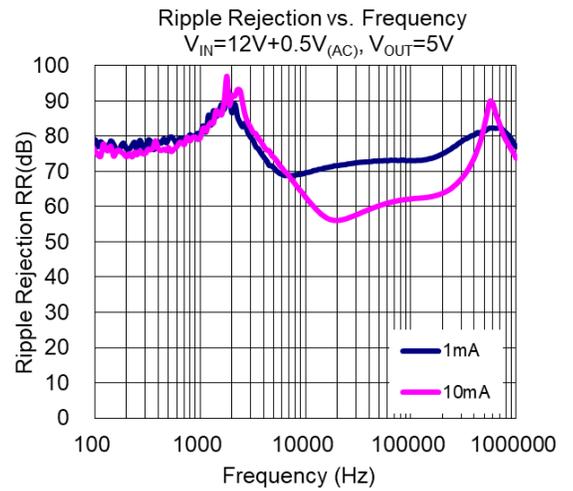
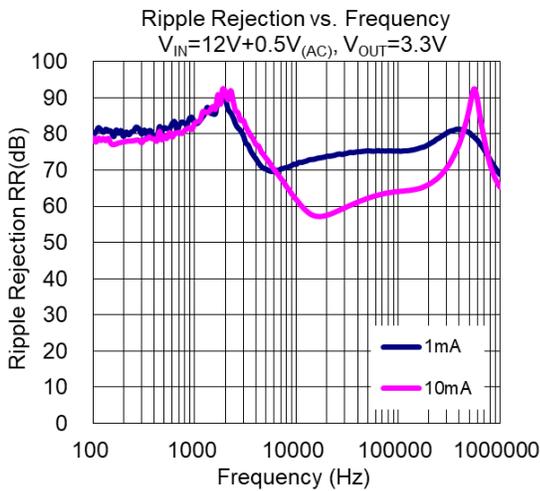
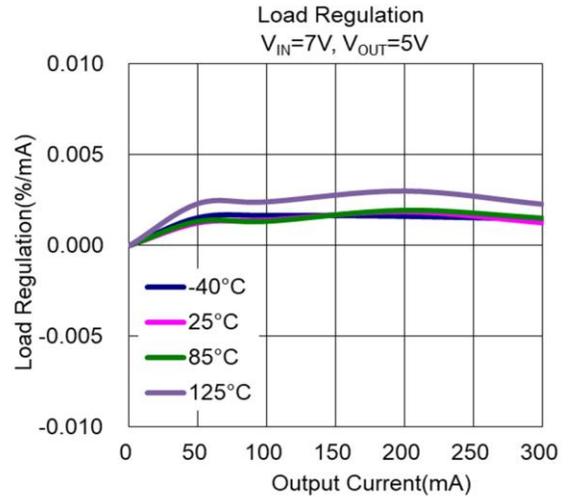
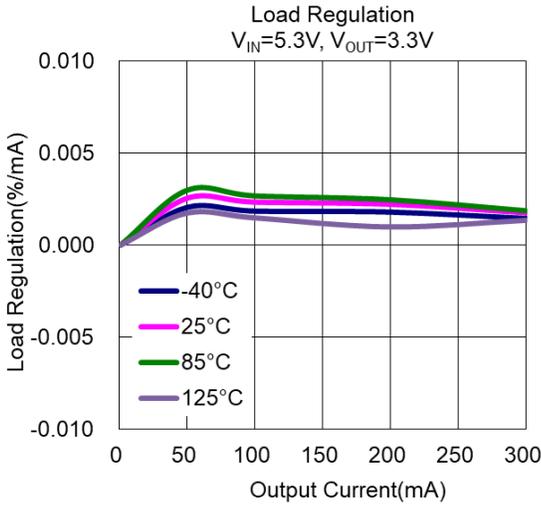
Performance Characteristics



Typical Characteristics (continued)

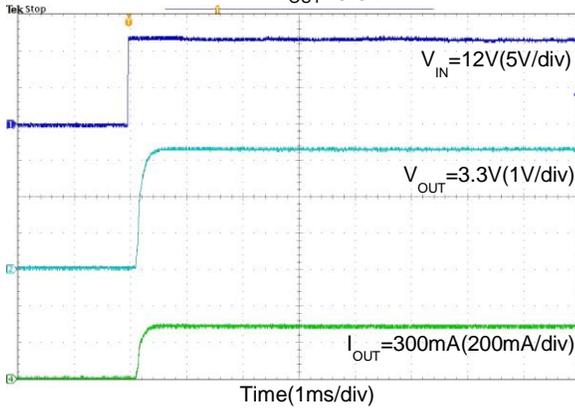


Typical Characteristics (continued)

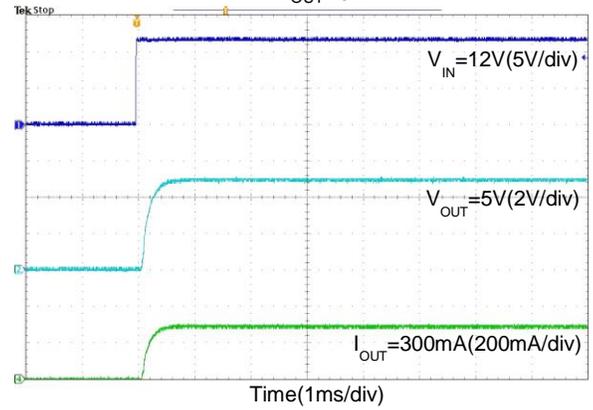


Typical Characteristics (continued)

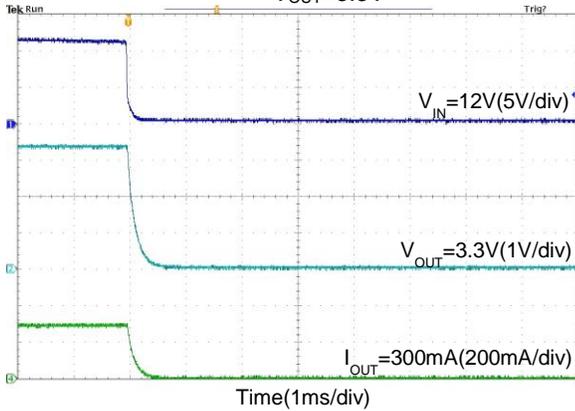
Power on
 $V_{OUT}=3.3V$



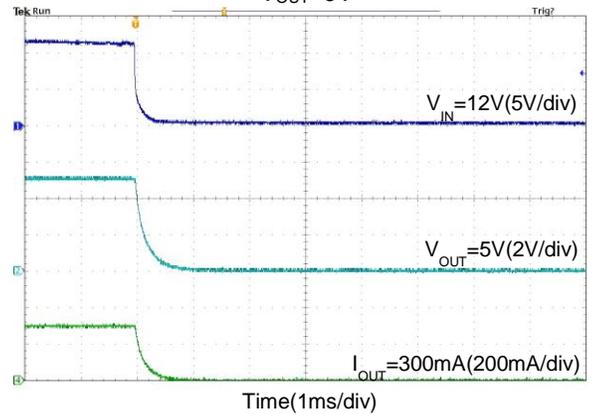
Power on
 $V_{OUT}=5V$



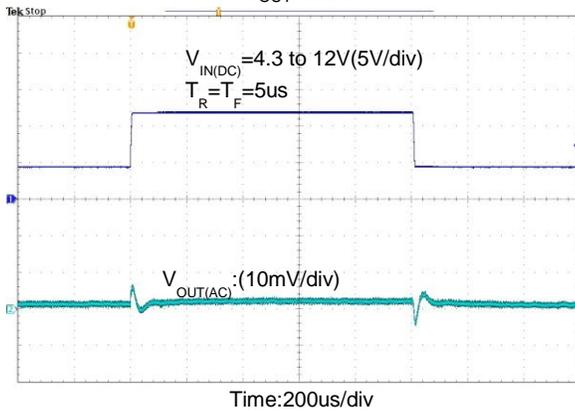
Power off
 $V_{OUT}=3.3V$



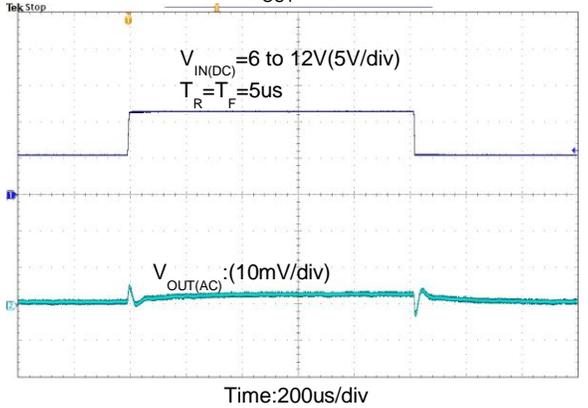
Power off
 $V_{OUT}=5V$



Line Transient Response
 $V_{OUT}=3.3V$

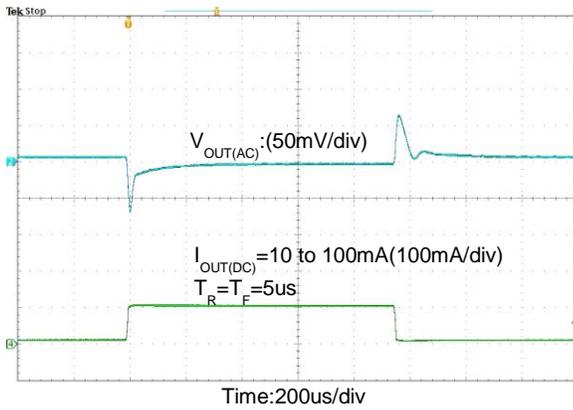


Line Transient Response
 $V_{OUT}=5V$

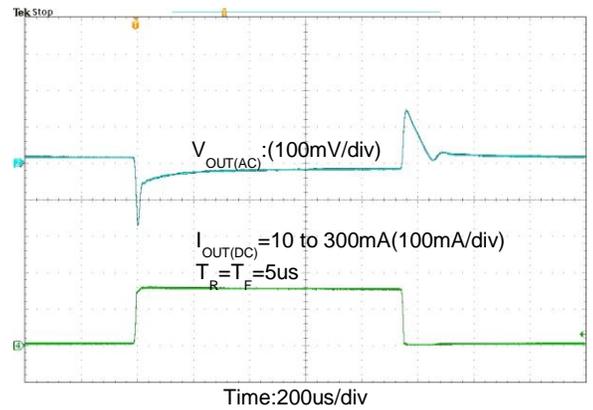


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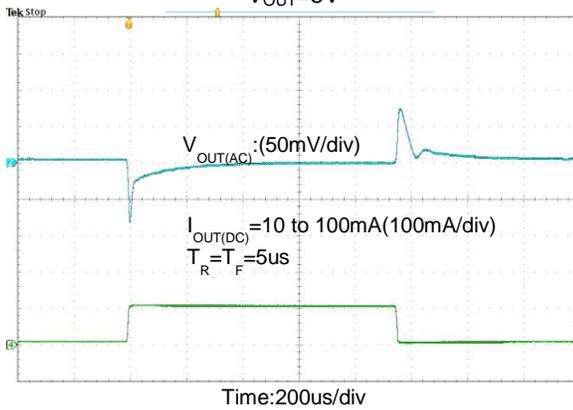
Load Transient Response
 $V_{OUT}=3.3V$



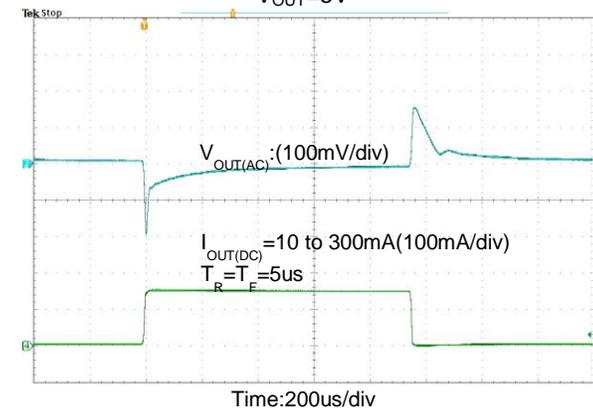
Load Transient Response
 $V_{OUT}=3.3V$



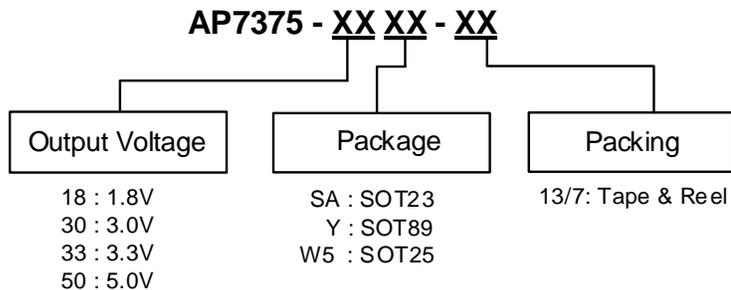
Load Transient Response
 $V_{OUT}=5V$



Load Transient Response
 $V_{OUT}=5V$



Ordering Information



Part Number	Package Code	Package	7"/13" Tape and Reel/Ammo	
			Quantity	Part Number Suffix
AP7375-XXSA-7	SA	SOT23	3000/Tape & Reel	-7
AP7375-XXY-13	Y	SOT89	2500/Tape & Reel	-13
AP7375-XXW5-7	W5	SOT25	3000/Tape & Reel	-7

Application Information

Output Capacitor

An output capacitor is required for the stability of the LDO. The recommended minimum output capacitance is 10 μ F. A ceramic capacitor is recommended, and temperature characteristics are X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place output capacitor as close as possible to VOUT and GND pins.

Input Capacitor

A 1 μ F ceramic capacitor is recommended to connect between VIN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both VIN and GND.

Current Limit and Short Circuit Protection

When output current at VOUT pin is higher than current-limit threshold or the VOUT pin is direct short to GND, the current-limit protection will be triggered and clamp the output current at a pre-designed level to prevent overcurrent and thermal damage.

Thermal Protection

The AP7375 has internal thermal sense and protection circuits. When excessive power dissipation happens on the device, such as short circuit at the output pin or very heavy load current with a large voltage drop across the device, the internal thermal protection circuit will be triggered, and it will shut down the power MOSFET to prevent the LDO from damage. As soon as excessive thermal condition is removed and the temperature of the device drops down, the thermal protection circuit will lease the control of the power MOSFET, and the LDO device goes to normal operation.

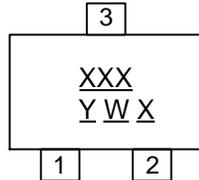
Layout Considerations

For good ground loop and stability, the input and output capacitors should be located close to the input, output, and ground pins of the device. The regulator ground pin should be connected to the external circuit ground to reduce voltage drop caused by trace impedance. Ground plane is generally used to reduce trace impedance. Wide trace should be used for large current paths from VIN to VOUT, and load circuit.

Marking Information

(1) SOT23

(Top View)

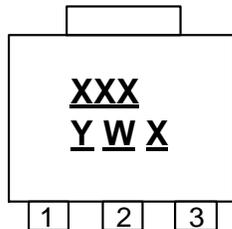


XXX : Identification Code
Y : Year 0 to 9
W : Week : A to Z : 1 to 26 week;
a to z : 27 to 52 week; z represents 52 and 53 week
X : Internal Code

Part Number	Package	Identification Code
AP7375-18SA-7	SOT23	H5A
AP7375-30SA-7	SOT23	H5B
AP7375-33SA-7	SOT23	H5C
AP7375-50SA-7	SOT23	H5D

(2) SOT89

(Top View)

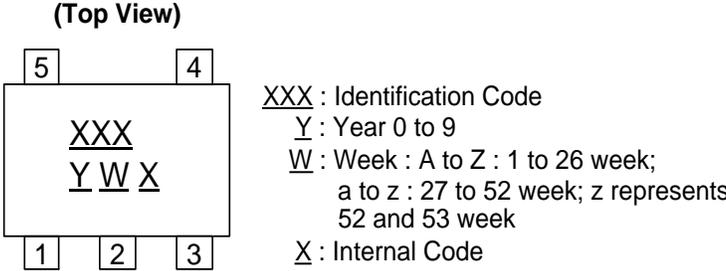


XXX : Identification code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week;
z represents 52 and 53 week
X : Internal code

Part Number	Package	Identification Code
AP7375-18Y-13	SOT89	H5A
AP7375-30Y-13	SOT89	H5B
AP7375-33Y-13	SOT89	H5C
AP7375-50Y-13	SOT89	H5D

Marking Information (continued)

(3) SOT25

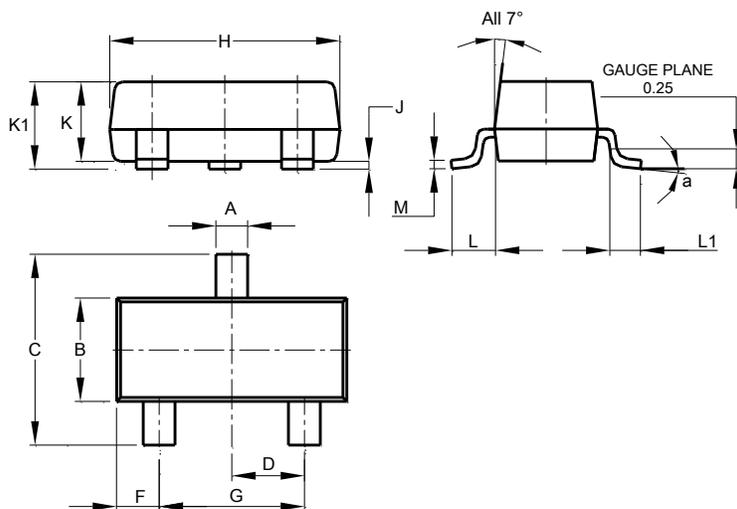


Part Number	Package	Identification Code
AP7375-18W5-7	SOT25	H5A
AP7375-30W5-7	SOT25	H5B
AP7375-33W5-7	SOT25	H5C
AP7375-50W5-7	SOT25	H5D

Package Outline Dimensions

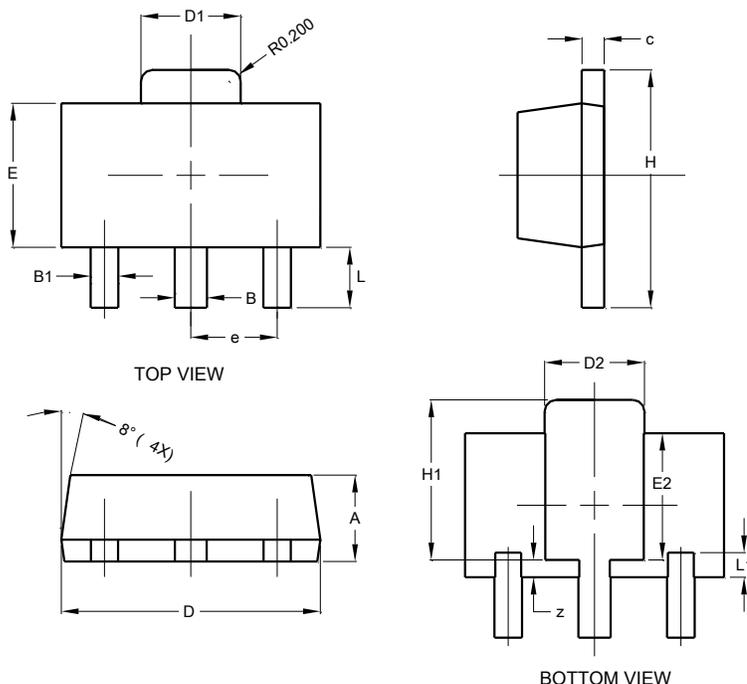
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SOT23



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

(2) SOT89

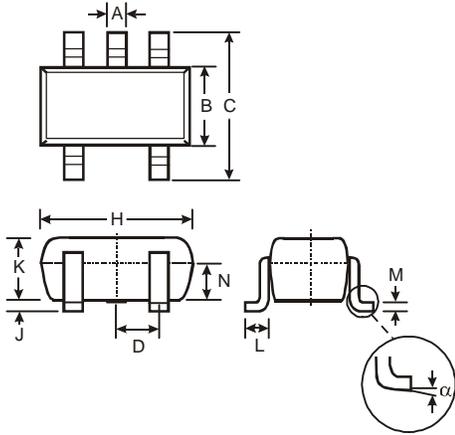


SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Package Outline Dimensions (continued)

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(3) SOT25

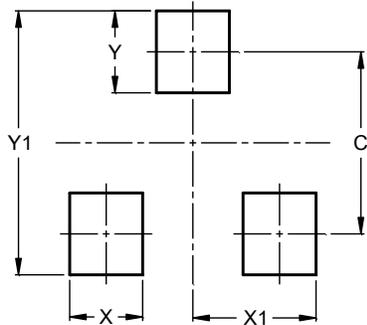


SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

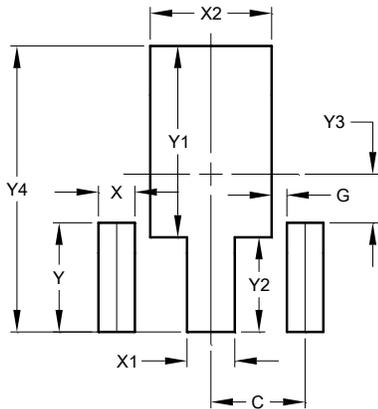
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) SOT23



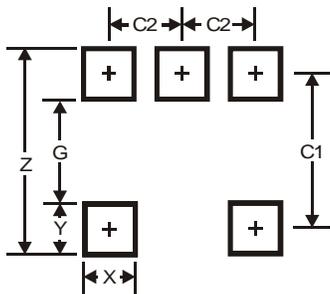
Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

(2) SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

(3) SOT25



Dimensions	Value
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

Mechanical Data

- Moisture Sensitivity:
 - SOT23/SOT25: Level 1 Per J-STD-020
 - SOT89: Level 3 Per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 [Ⓔ]
- Weight:
 - SOT89: 0.054 grams (Approximate)
 - SOT23: 0.009 grams (Approximate)
 - SOT25: 0.018 grams (Approximate)

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